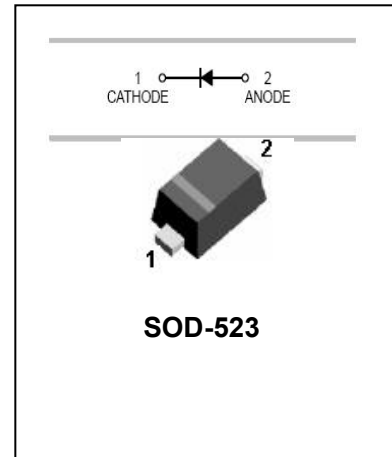


## Low leakage Diode

### FEATURES

- Ultra small plastic SMD package.
- Switching time: typ.0.6us.
- Continuous reverse voltage: max.75V.
- Repetitive peak reverse voltage: max.85V



### APPLICATIONS

- Low leakage current switching in surface mounted circuits.

### ORDERING INFORMATION

Type No.	Marking	Package Code
BAS716	BA	SOD-523

### MAXIMUM RATING @ Ta=25°C unless otherwise specified

Characteristic	Symbol	Limits	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	85	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Reverse Voltage	$V_R$		
RMS Reverse Voltage	$V_{R(RMS)}$	60	V
Forward Continuous Current	$I_{FM}$	250	mA
Repetitive Peak Forward Current	$I_{FRM}$	500	mA
Non-Repetitive Peak Forward Surge Current	$I_{FSM}$	4.0	A
@t=1.0μs		1.0	
@t=1.0ms		0.5	
Power Dissipation	$P_d$	250	mW
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	500	°C/W
Operating Junction Temperature Range	$T_j$	150	°C
Storage Temperature Range	$T_{STG}$	-65 to +150	°C

**ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

Characteristic	Symbol	Min	Typ	MAX	UNIT	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	85	130	-	V	$I_R=100\mu A$
Forward Voltage	$V_{FM}$	-	-	0.8 0.9 1.1 1.25	V	$I_F=1mA$ $I_F=10mA$ $I_F=50mA$ $I_F=150mA$
Reverse Leakage Current	$I_R$	-	-	5.0 80	nA	$V_R=75V$ $V_R=75V, T_j=150^\circ C$
Junction Capacitance	$C_j$	-	1.5	3.0	pF	$V_R=0V, f=1.0MHz$
Reverse Recovery Time	$t_{rr}$	-	0.6	3	us	$I_F=I_R=10mA, I_{rr}=0.1*I_R$

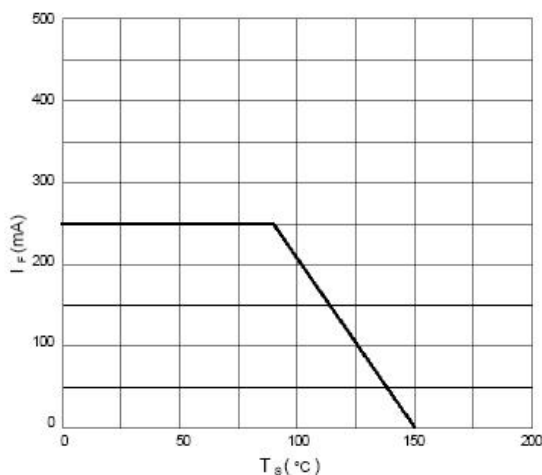
**TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**


Fig.1 Maximum permissible continuous forward current as a function of soldering point temperature.

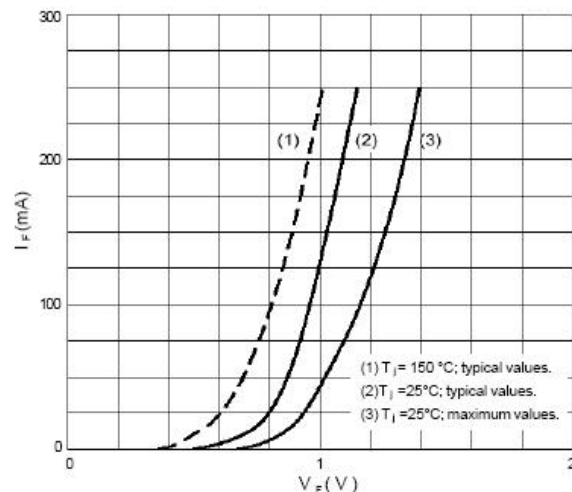


Fig.2 Forward current as a function of forward voltage.

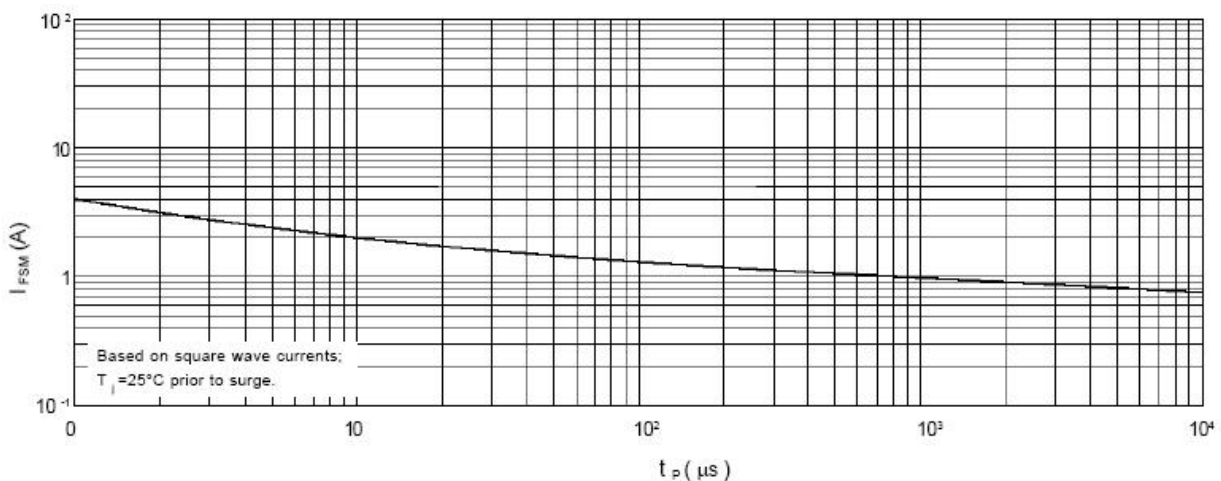


Fig.3 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

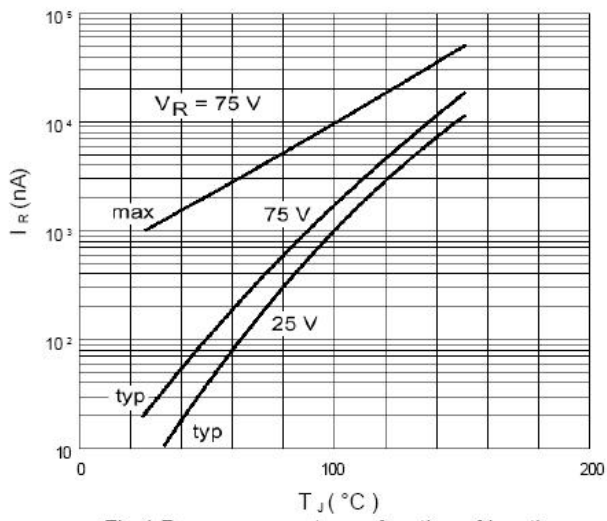


Fig.4 Reverse current as a function of junction temperature.

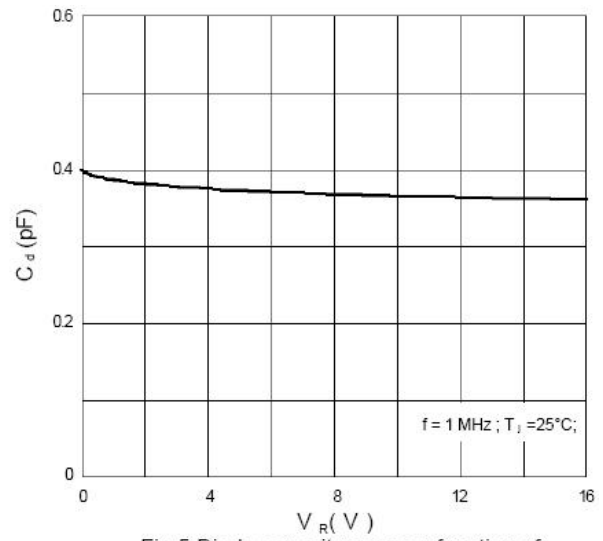


Fig.5 Diode capacitance as a function of reverse voltage; typical values.